## NSN 5961-00-823-9972

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View Online at https://aerobasegroup.com/nsn/5961-00-823-9972

#### **Inclosure Material:**

Metal

**Overall Length:** 

0.535 inches

## **Mounting Facility Quantity:**

1

#### Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-63

#### Electrode Internally-electrically Connected To Case:

Collector

**Mounting Method:** 

Threaded stud

#### Features Provided:

#### Hermetically sealed case

**Overall Width Across Flats:** 

0.875 inches

#### **Thread Size:**

0.312 inches

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

100.0 breakdown voltage, collector-to-base, emitter open and 8.0 breakdown voltage, emitter-to-base, collector open and 80.0 breakdown voltage, collector-to-emitter, base open

#### **Current Rating Per Characteristic:**

20.00 amperes source cutoff current and 5.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

100.0 watts small-signal input power, common-collector

#### **Transfer Ratio:**

225.0 static forward current transfer ratio, common-emitter

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius case

## **Special Features:**

Junction pattern arrangement: npn

## Thread Series Designator:

Unf

## **Terminal Type And Quantity:**

3 tab, solder lug

## Shelf Life:

N/a

## Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0

